



SANYO Semiconductors

DATA SHEET

LA8120T — Monolithic Linear IC

AGC Amplifier with Step Gain Control

Overview

The LA8120T bipolar monolithic IC is an AGC amplifier with driver amplifier for analog-to-digital converters. It is ideally suited for use with receiver systems that receive QPSK and/or QAM data transmissions.

Functions

- IF AGC control
- IF AGC amplifier
- IF Step Gain Controlled Amplifier
- Driver amplifier

Applications

- Digital CATV
- Cable modem receivers
- IP Telephony receivers

Specifications

Absolute Maximum Ratings at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum Supply voltage	$V_{CC\text{ max}}$	Pin 1	7.0	V
Circuit Voltages	$V\text{ max}$	Pin 4, Pin 5	$V_{CC\text{ op}}$	V
Circuit Current	I_6 I_7	Pin 6 sink current Pin 7 sink current	2 2	mA
Allowable Power Dissipation	$P_d\text{ max}$	$T_a \leq 85\text{ }^\circ\text{C}^*$	220	mW
Operating Temperature	T_{opr}		-20 to +85	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

*Mounted on PCB : 20.0mm x 10.0mm x 0.8 mm, paper phenol.

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SANYO Semiconductor Co., Ltd.

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LA8120T

Recommended Operating Conditions at Ta = 25 °C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended Supply Voltage	V _{CC}	Pin 1	5.0	V
Operating Supply Voltage Range	V _{CC op}	Pin 1	4.5 to 5.5	V

Electrical Characteristics

AC Characteristics at Ta = 25 °C, V_{CC} = 5.0 V

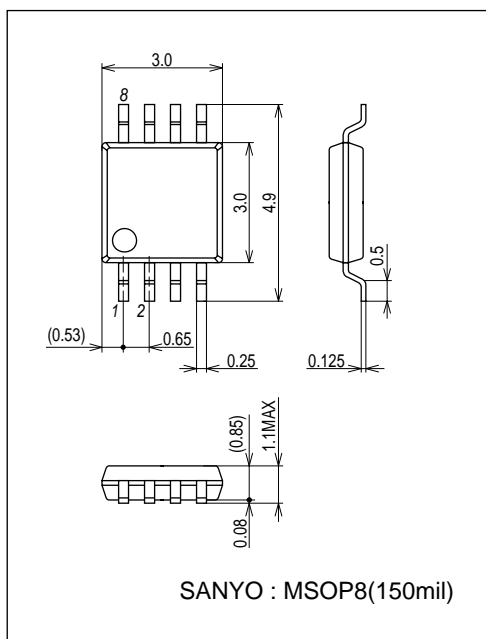
Parameter	Symbol	Pin No.	Conditions	Ratings			Unit		
				min	typ	max			
Circuit Current	I _{total}	1	No Signal	*1	25	30	35	mA	
IF Input Frequency Range	f(in)	2, 3	fc : -3 dB	*1	30		100	MHz	
Noise Figure	NF	6, 7	V4 = 3.0 V, f = 45 MHz	Pin 5 : V _{CC}	*2		5		dB
			V4 = 3.0 V, f = 45 MHz	Pin 5 : GND	*2		6		dB
			V4 = 3.0 V, f = 45 MHz	Pin 5 : OPEN	*2		8		dB
Intermodulation	IM3	6/2, 3 7/2, 3	f1 = 44 MHz, f2 = 45 MHz Input = 90 dBμ/Tone, Output = 104 dBμ/Tone	*1	50			dBc	
Total Amplifier Gain	G(AGC1)	6/2, 3 7/2, 3	V4 = 3.0 V, f = 45 MHz	Pin 5 : V _{CC}	*1	45.5	48	50.5	dB
	G(AGC2)	6/2, 3 7/2, 3	V4 = 3.0 V, f = 45 MHz	Pin 5 : GND	*1	41.5	44	46.5	dB
	G(AGC3)	6/2, 3 7/2, 3	V4 = 3.0 V, f = 45 MHz	Pin 5 : OPEN	*1	33.5	36	38.5	dB
AGC Range 1	GR1	6/2, 3 7/2, 3	IF Output Level < ±1 dB, f = 45 MHz	*1	40			dB	
IF Output Level	V _{O(IF)}	6, 7	Output Level, f = 45 MHz	*1		1.0		Vp-p	
AGC Control Max. Voltage	V4H	4	Gain Max.	*1	2.5		3	V	
AGC Control Min. Voltage	V4L	4	Gain Min.	*1	0		0.5	V	
Input impedance	Z _{in}	2, 3	V4 = 0 V, f = 45 MHz	*3		1 // 4.9		kΩ // pF	

*1 : Measurement circuit 1, *2 : Measurement circuit 2, *3 : Measurement circuit 3

Package Dimensions

unit : mm (typ)

3245B

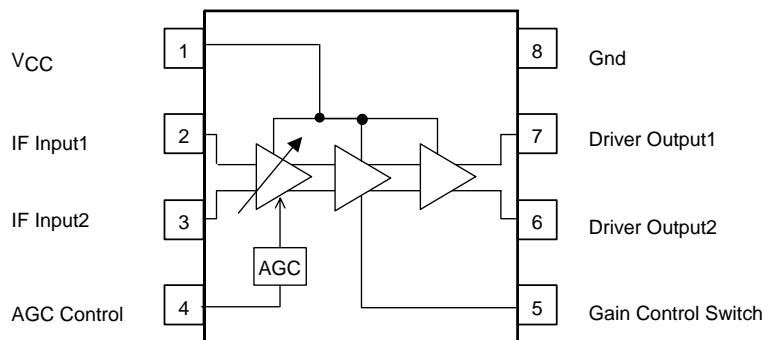


LA8120T

Pin Functions

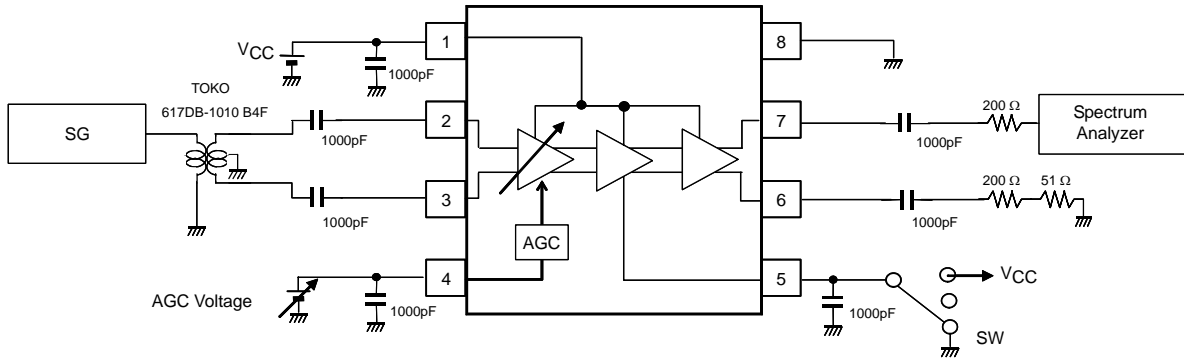
Pin Number	Pin Name	Equivalent Circuit
1	V _{CC}	
2 3	IF Input	
4	AGC Control	
5	Gain Control Switch	
6 7	Driver Output	
8	GND	

Block Diagram

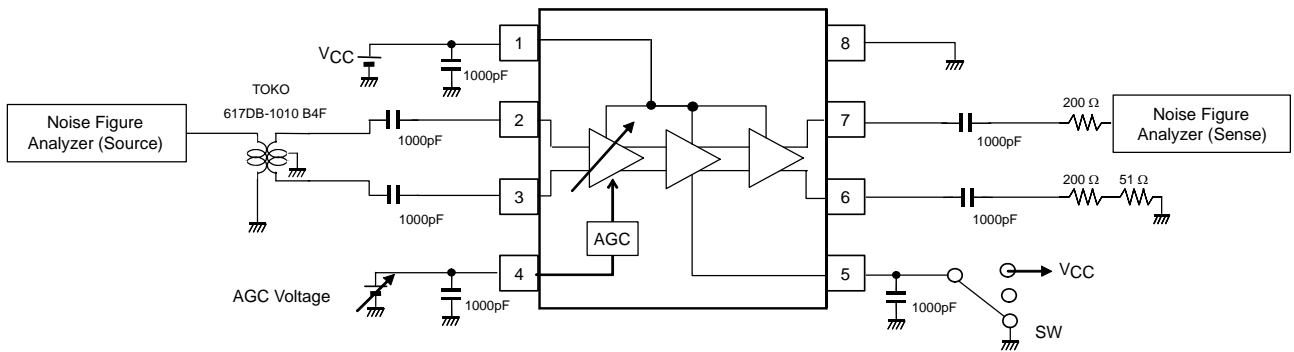


LA8120T

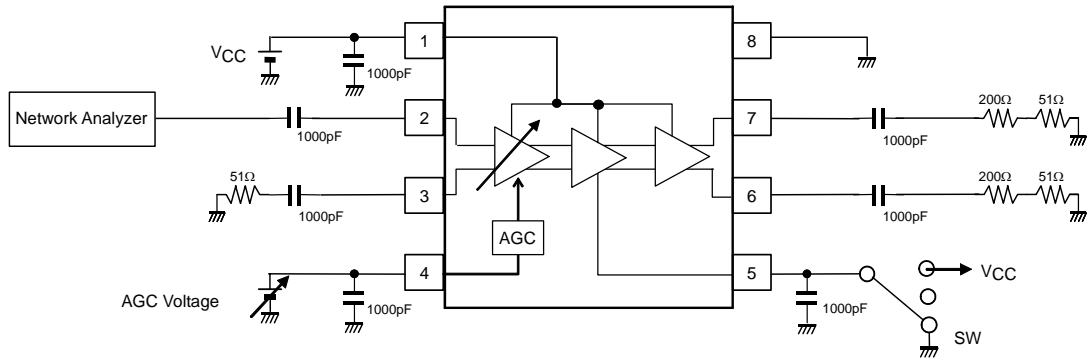
LA8120T Gain, Measurement Circuit 1



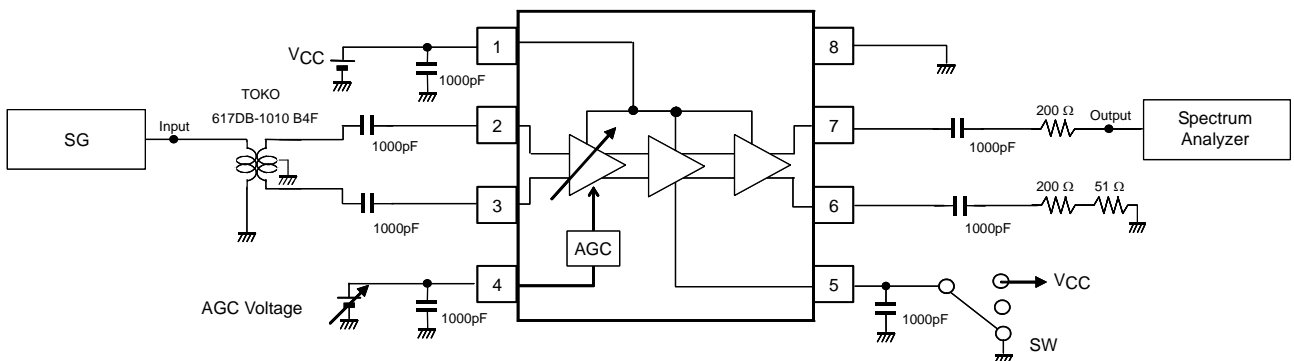
LA8120T Noise Figure Measurement Circuit 2



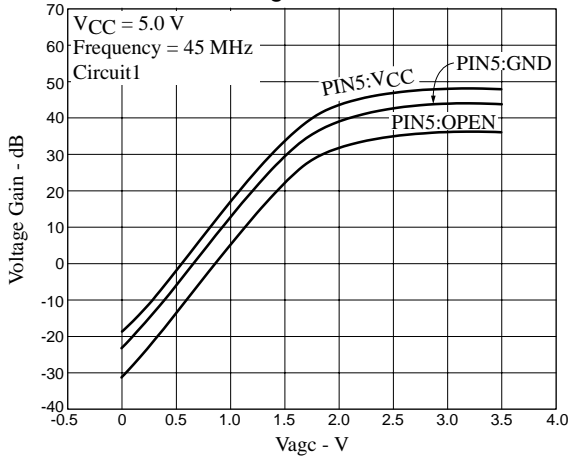
LA8120T Input Impedance Measurement Circuit 3



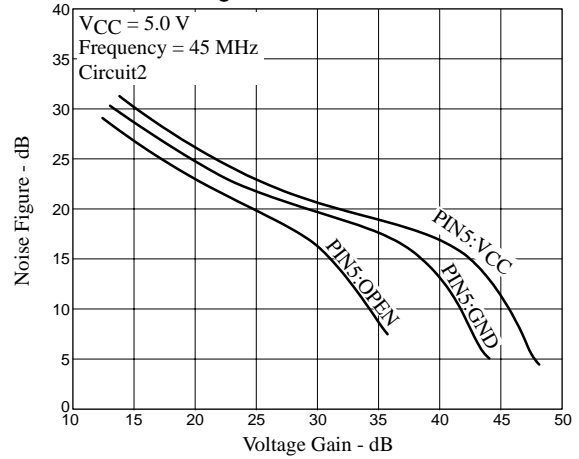
LA8120T Intermodulation Measurement Circuit 4



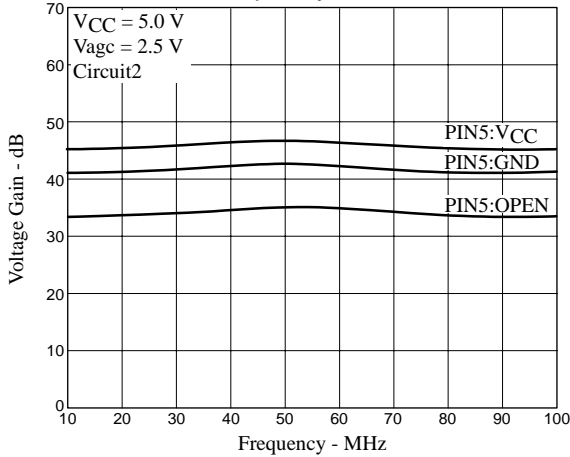
Gain - Vagc Characteristic



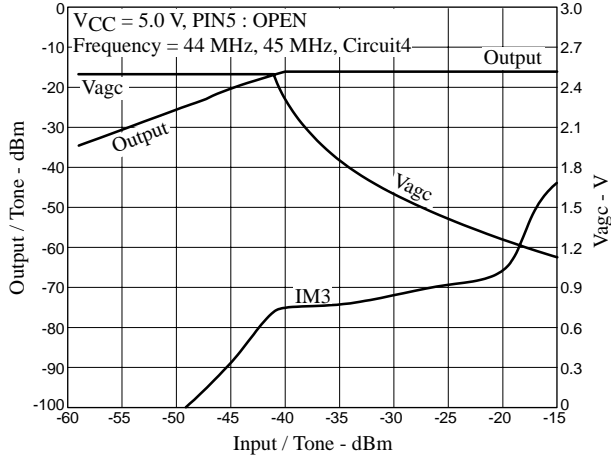
Noise Figure - Gain Characteristic



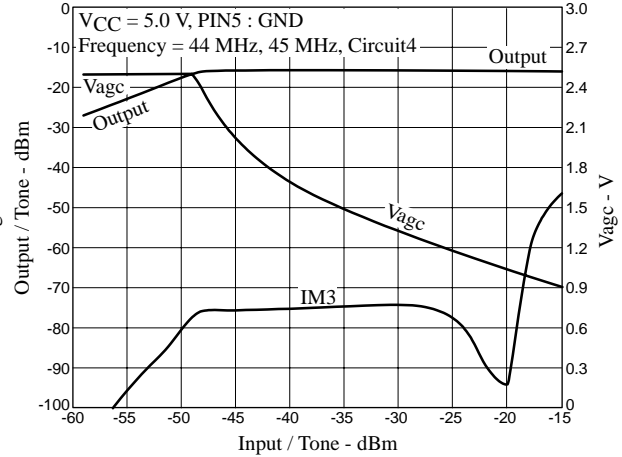
Gain - Frequency Characteristic



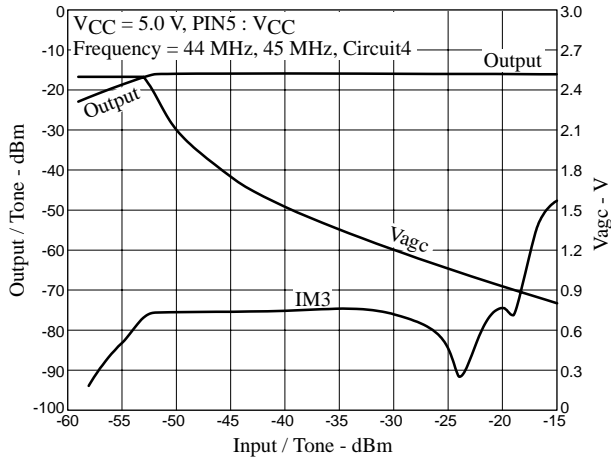
Intermodulation Characteristic



Intermodulation Characteristic



Intermodulation Characteristic

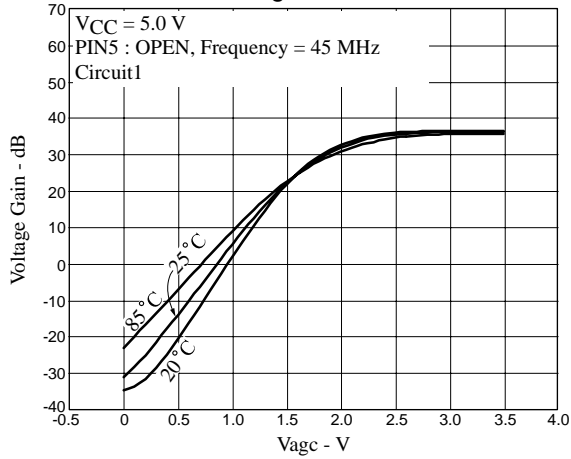


The vertical axis (Output/Tone) on this graph shows the values displayed by the spectrum analyzer for circuit 4.

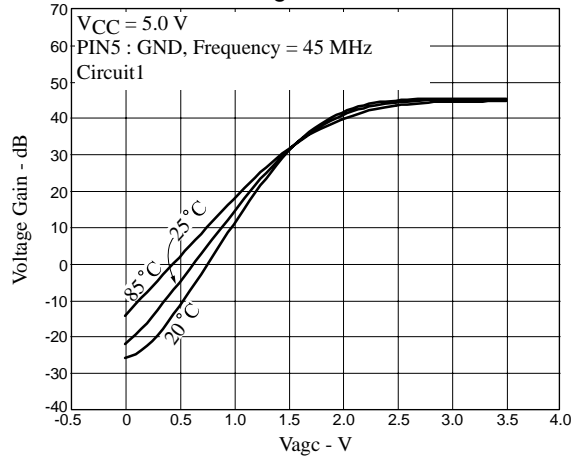
The actual output power for the corresponding pins is given by the following formula.

$$\{\text{output power [dBm]}\} = \{\text{displayed value [dBm]}\} + 10 \cdot \log(250 \Omega / 50 \Omega)$$

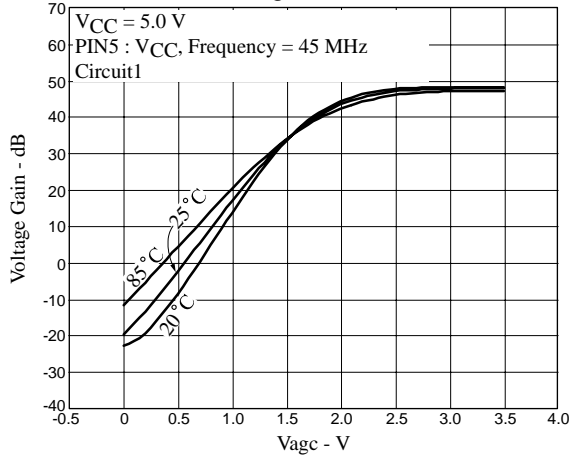
Gain - V_{agc} Characteristic



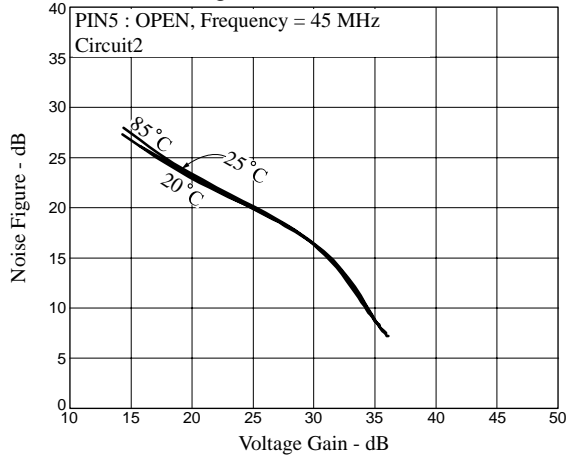
Gain - V_{agc} Characteristic



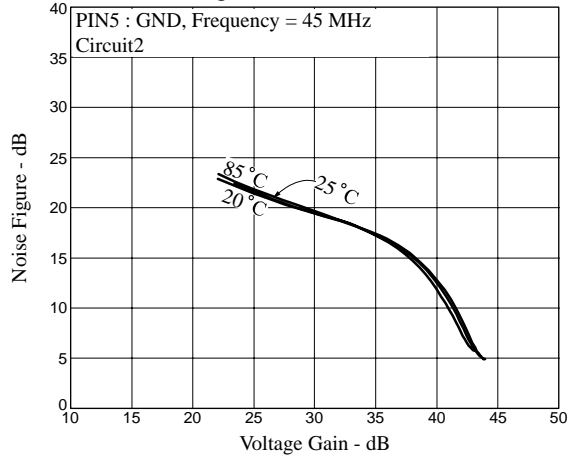
Gain - V_{agc} Characteristic



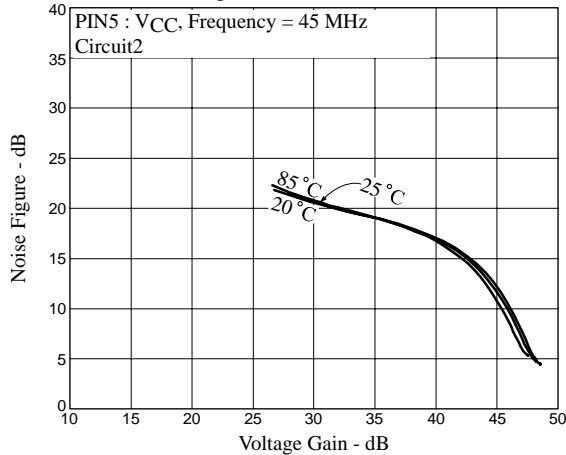
Noise Figure - Gain Characteristic



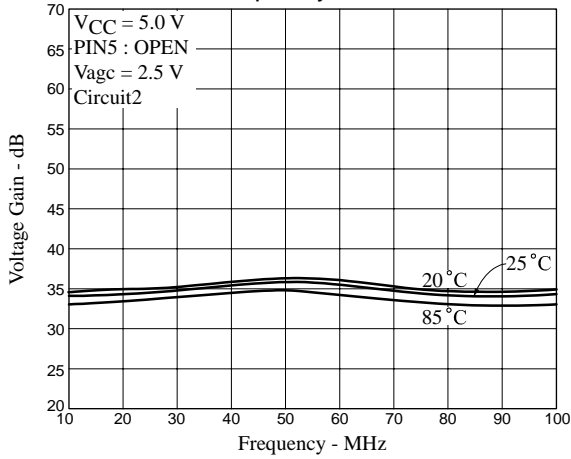
Noise Figure - Gain Characteristic



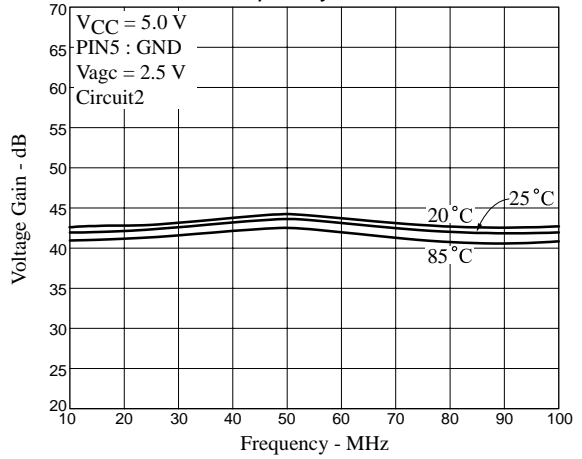
Noise Figure - Gain Characteristic



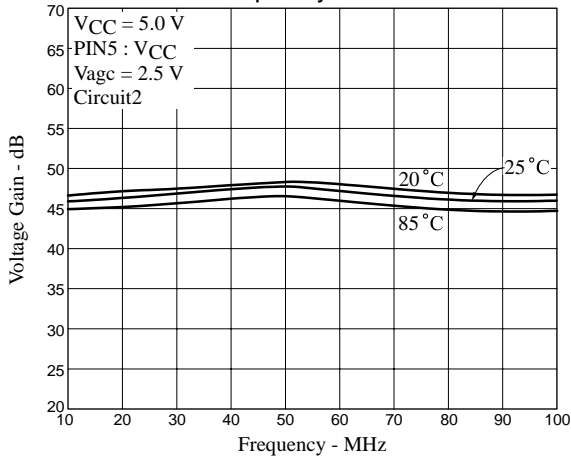
Gain - Frequency Characteristic



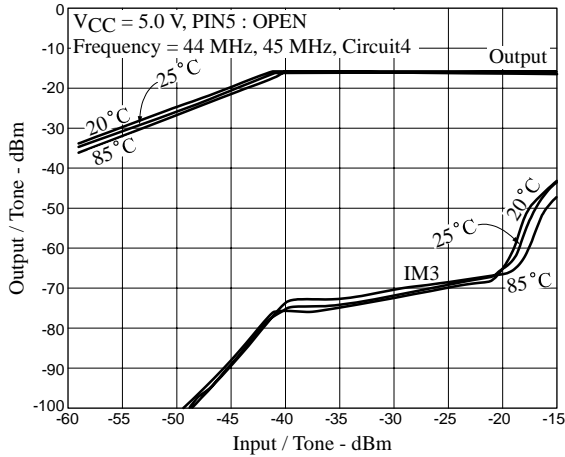
Gain - Frequency Characteristic



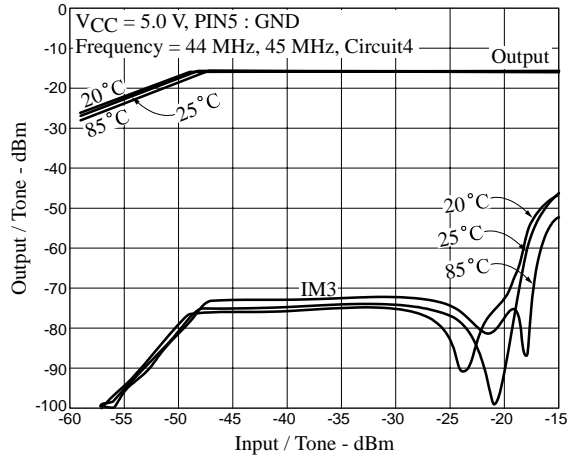
Gain - Frequency Characteristic



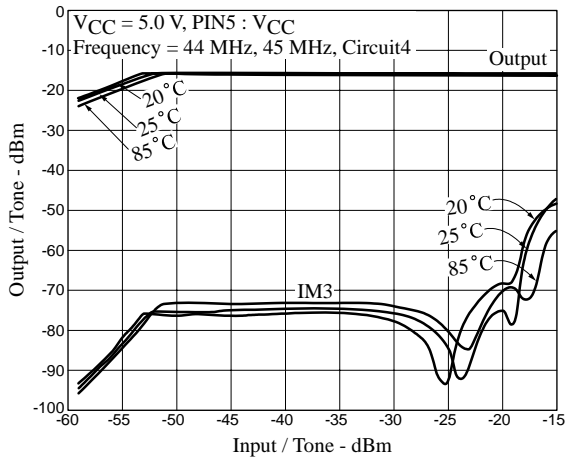
Intermodulation Characteristic



Intermodulation Characteristic



Intermodulation Characteristic



The vertical axis (Output/Tone) on this graph shows the values displayed by the spectrum analyzer for circuit 4.

The actual output power for the corresponding pins is given by the following formula.

$$\{\text{output power [dBm]}\} = \{\text{displayed value [dBm]}\} + 10 \cdot \log(250 \Omega / 50 \Omega)$$

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